

Declaration of Conformity

For the following equipment(s):

DDR3 DIMM / DDR3 SODIMM / DDR4 DIMM / DDR4 SODIMM

(Product Name)

xGB DDR3\$ # & @ DIMM / xGB DDR4\$ # & @ DIMM

x: DIMM Density

\$: DIMM Voltage (empty: 1.5V, L:1.35V)

#: DIMM Data rate

&: Function Support: (empty, ECC · w/Reg)

@: PCB type: (empty: Standard, Low-Profile, VLP: Very Low-Profile, ULP: Ultra Low-Profile)

DIMM type include: (DIMM, REG DIMM, SO DIMM)

(Model Designation / Brand Name)

Innodisk Corporationn

(Manufacturer Name)

5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 22161, Taiwan (R.O.C)

(Manufacturer Address)

is here with confirmed to comply with the requirements set out in the Council Directive on the Approximation of the Laws of the Member States relating to Electromagnetic Compatibility Directive (2014/30/EU). For the evaluation regarding the Electromagnetic Compatibility (2014/30/EU) and RoHS (2011/65/EU) and (EU /2015/863), the following standards are applied:

EN 55032: 2015 / A11: 2020

CISPR 32: 2015 (Ed 2.0) / C1: 2016

EN 61000-3-2: 2014

EN 61000-3-3: 2013

EN 55035: 2017 / A11: 2020

IEC 61000-4-2: 2008; IEC 61000-4-3: 2006 + A1: 2007 + A2: 2010;

IEC 61000-4-4: 2012; IEC 61000-4-5: 2014 + A1: 2017;

IEC 61000-4-6: 2013 + COR1: 2015; IEC 61000-4-8: 2009;

IEC 61000-4-11: 2004 + A1: 2017

EN IEC 63000 : 2018

The following manufacturer / importer or authorized representative established within the EU is responsible for this declaration:

Innodisk Corporation

(Company Name)

5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 22161, Taiwan, R.O.C

(Company Address)

Person responsible for making this declaration:

Yi Chuan Chen

(Name, Surname)

Quality Assurance Division / Manager

(Position / Title)

Taipei

(Place)

March 18 2022

(Date)

Yi Chuan Chen
(Legal Signature)